#### Journal of Alloys and Compounds 656 (2016) 555-567

Contents lists available at ScienceDirect

# SEVIER jo



### journal homepage: http://www.elsevier.com/locate/jalcom

Journal of Alloys and Compounds

## Hydrogen solubility and vacancy concentration in nickel single crystals at thermal equilibrium: New insights from statistical mechanics and *ab initio* calculations



#### Arnaud Metsue<sup>\*</sup>, Abdelali Oudriss, Xavier Feaugas

Laboratoire des Sciences de l'Ingénieur pour l'Environnement, UMR CNRS 7356, Université de La Rochelle, Avenue Michel Crépeau, 17000 La Rochelle, France

#### ARTICLE INFO

Article history: Received 20 July 2015 Received in revised form 16 September 2015 Accepted 28 September 2015 Available online 1 October 2015

Keywords: Hydrogen absorbing materials Metals and alloys Gas–solid reactions Vacancy formation Computer simulations Thermodynamic modeling

#### ABSTRACT

The hydrogen solubility and the vacancy concentration in Ni single crystals at thermal equilibrium have been determined from a combination of mechanical statistics and *ab initio* calculations of the Gibbs free energy up to  $P_{H2} = 0.1$  GPa and 1700 K. We consider that the H atoms can be located in the interstitial sites but also in the displacement field generated by a vacancy to create H-vacancy clusters. The solution and the H-vacancy clusters defect formation free energies are expressed as a sum of a vibration and an electronic contributions. We find that the H-vacancy interactions are significant inside the vacancy core and we show that the H-rich vacancy clusters have a negative free energy at high P<sub>H2</sub>, similarly to the case of fcc Fe. Then, we compute the H solubility and the vacancy concentration for a wide range of  $\mu_{H2}$ . The calculated solubility at P<sub>H2</sub> = 1 bar is in agreement with previous experimental data. Although the vibration contribution dominates the temperature dependence of the solution and formation free energies, the electronic excitations only can lead to a marked deviation of the solubility at high temperature. The vacancy formation is promoted at high P<sub>H2</sub> with a significant contribution to the trapping of the H atoms inside the vacancy core at low temperature. However, the total number of vacancies remains too small and has a minor effect on the apparent solubility in single crystals up to P<sub>H2</sub> = 0.1 GPa.

© 2015 Elsevier B.V. All rights reserved.

#### 1. Introduction

The interactions between hydrogen and materials can strongly affect the physical and the chemical properties of the host matrix [1]. In the case of metals, the insertion of H in the interstitial sites and/or around crystalline defects can lead to reversible or irreversible effects on the mechanical properties and favored embrittlement at different scales (see Refs. [2–8] for a partial review on the topic). Therefore, the apparent or effective solubility of hydrogen in metals at a representative scale of the microstructure has to be known to design tough materials under aggressive environmental conditions. In the present study, we focus on the solubility of hydrogen in nickel since this material and nickel-based alloys are commonly used in metallurgical industry and have many technological applications.

The apparent solubility of hydrogen in polycrystalline nickel has been investigated extensively for a long time ago since the

\* Corresponding author. *E-mail address:* arnaud.metsue@univ-lr.fr (A. Metsue). pioneering work of Sieverts [9]. It can be accessed from electrochemical permeation tests [10-17] or from gas equilibratedquench-analyze experiments [18-21]. By using the latter technique, it has been shown that polycrystalline samples in equilibrium with a  $H_2$  gas atmosphere at  $P_{H2}=1$  atm can incorporate between 3.2  $\times$   $10^{-5}$  H/Ni and 4.5  $\times$   $10^{-5}$  H/Ni at ambient temperature and up to  $3.4 \times 10^{-4}$  H/Ni at 1000 K [9,18,21–23]. The temperature dependence of the solubility shows a large deviation from the Arrhenius law for T > 1000 K [18]. Unlike the case of polycrystalline Ni, few data on the solubility of H in single crystals are available in the literature. The solubility measurements of Eichenauer et al. [24] and Stafford and McLellan [18] from gas equilibrated experiments at  $P_{H2} = 1$  atm point up that the solubility is about two times lower in single crystals compared to polycrystalline samples in the 650 K - 1000 K temperature range. The difference of solubility between single crystals and polycrystals becomes smaller at higher temperature and the deviation from the Arrhenius law is unclear in single crystals.

The deviation of the solubility from the Arrhenius law in polycrystalline Ni has been attributed to the presence of interstitial sites with differing energies where the H atoms can be located [11] or to the H-vacancy interactions [25,26]. Actually, crystalline defects, such as dislocations, grain boundaries or point defects, can influence the apparent solubility of H in metals trough a trapping phenomenon or a short-circuit diffusion path [1,5,27]. Reversible and irreversible traps for hydrogen can be distinguished from their depth energy levels according to the classification given by Pressouyre [27]. The displacement fields induced by dislocations, coherent precipitates and vacancies are considered as reversible traps with an energy level between 0.1 eV and 0.4 eV [5,28-31] while dislocation and vacancy cores are acting as irreversible traps with an energy level above 0.5 eV [1,5,32–35]. For nickel, the H trap binding energy in the vacancy core has been evaluated between -0.28 eV and -0.22 eV from recent *ab initio* calculations at 0 K [36–39]. In addition, it has been suggested that the vacancies in this metal can incorporate up to 6 H atoms to form H-vacancy clusters at static conditions [37,39–43] and may lead to a significant evolution of the apparent solubility. However, such H-rich vacancy clusters become unstable under high H<sub>2</sub> chemical potential in the case of fcc Fe [39] and the stability of the H-rich defects in Ni proposed by Connétable et al. [37] is questionable.

The hydrogen-vacancy interactions may have major implications in the degradation mechanisms of metals [44–48]. In particular, the lattice parameters of the metal-hydrogen alloys decrease with the incorporation of H and indicate the formation of new vacancies, called superabundant vacancies (SAV), at high P<sub>H2</sub> [4,46,49–51]. A linear relation between the vacancy concentration and the hydrogen content in nickel has been found for high hydrogen pressures ( $P_{H2} = 2.4-5.5$  GPa) and high temperatures (940–1200 K) [52] where nearly stoichiometric Ni–H hydrides are stable [4,53-55]. The formation of SAV has been also observed in electrodeposited nanocrystalline materials at room temperature after an electrochemical charging step [49,56]. These superabundant vacancy concentrations may arise from a large decrease of the vacancy formation energy in metal-hydrogen solid solutions compared to H-free samples [41]. Several thermodynamic models have been used to explain the superabundant vacancy formation mechanism and the stability of such H-decorated vacancies [25,39,40,57,58]. These models have been formulated on the base of the thermodynamic equilibrium involving the solution energy of H incorporation in the interstitial sites of a perfect crystal and the formation energy of H-vacancy clusters. The distribution of the H atoms and the vacancies has been taken into account from the Maxwell–Boltzmann statistics [59], the Fermi–Dirac distribution function [25,42,60–62] or from a linear mixing of the Ni–H solid solution [40]. However, no non-configurational entropic contributions have been taken into account in these models and no clear correlations have been made between the presence of vacancies and the macroscopic solubility of hydrogen in nickel so far.

In this paper, we determine the solubility of hydrogen and the vacancy concentration in nickel single crystals at thermodynamic equilibrium for a wide range of H<sub>2</sub> chemical potentials from ab initio calculations. We calculate the solution Gibbs free energy of incorporation of H in the interstitial sites of a perfect crystal. We extend the calculations to the formation Gibbs free energy of Hvacancy clusters where H can be located inside the vacancy core or in the elastic displacement field generated by the defect. The Gibbs free energy is taken as a sum of lattice vibrations and electronic excitations contributions. Then, the macroscopic apparent solubility and the vacancy concentration are determined from statistical mechanics involving the configuration entropy and the Gibbs free energies by minimizing the total free energy expressed in the grand canonical potential. This procedure has been proposed for Al [61] and austenitic steel (Fe- $\gamma$ ) [60]. Finally, we compare our results with previous gas equilibrated-quench-analyze experiments at  $P_{H2} = 1$  bar where the chemical potential of gaseous hydrogen is calculated at finite temperature including the rotation, the translation and the vibration modes of the  $H_2$  molecule. Based on these results, the thermodynamic conditions of the previous experimental results found in the literature are discussed.

#### 2. Methods

## 2.1. Energy and entropy of bulk Ni and Ni–H alloys at finite temperature

The determination of the solubility of hydrogen in nickel single crystals from ab initio calculations at finite temperature needs the computation of the energy and the entropy of perfect Ni, Ni crystal containing a vacancy and Ni-H alloys. For the latter, we consider H in the interstitial sites of a perfect crystal and in the displacement field generated by a vacancy. We use the results obtained in our previous study dedicated to the calculation of the vacancy concentration in Ni at thermal equilibrium for the energy and the entropy of the crystal containing a H-free vacancy [63]. In the case of Ni-H alloys in a vacancy-free crystal, hydrogen is incorporated in the octahedral site and in the tetrahedral site, even several experimental and ab initio studies suggest that H atoms occupy octahedral sites only [22,36,37,64,65]. The procedure is extended to the incorporation of H in the interstitial sites of the displacement field generated by a vacancy in the crystal. The location of H in the Hvacancy clusters investigated in this study is shown in Fig. 1. These clusters involve the O1 and T1 sites inside the vacancy core, the O2 site tangent to it and other sites (T2, O3, T3) in the short-range elastic displacement field of the defect.

*Ab initio* calculations are based on the density functional theory [66,67] (DFT) within the PBE functional [68] implemented in the PWSCF code of the Quantum Espresso package [69]. We use pseudopotentials built with the projected augmented wave method [70,71] to describe the ion—electrons interactions of Ni and H. The plane wave cutoff of the pseudopotentials is set to 60 Ry and a Fermi—Dirac smearing of 0.002 Ry is used to broaden the electronic density of states.

The energy and the entropy of pure Ni and Ni–H alloys are calculated with a supercell built on a  $4 \times 4 \times 4$  repetition of the primitive Ni lattice (64 Ni atoms). Increasing the supercell size to a  $5 \times 5 \times 5$  repetition of the primitive lattice (125 Ni atoms) decreases the H solution energy of 4 meV and the vacancy formation



**Fig. 1.** Location of the H atom in the H-vacancy clusters investigated in this study. The vacancy is at the origin of the coordinate framework and the H atom is located in the interstitial sites inside the vacancy core (O1 and T1), tangent to it (O2) or in the elastic displacement field (T2, O3, T3).

Download English Version:

# https://daneshyari.com/en/article/1607703

Download Persian Version:

https://daneshyari.com/article/1607703

Daneshyari.com